

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - **20** to **100** Volts
FORWARD CURRENT - **5.0** Amperes

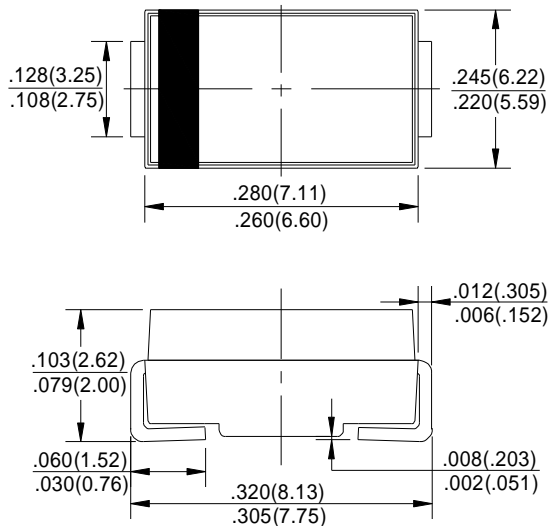
FEATURES

- Metal-Semiconductor junction with guard ring
- Epitaxial construction
- Low forward voltage drop
- High current capability
- The plastic material carries UL recognition 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: Molded Plastic
- Polarity: Color band denotes cathode
- Weight: 0.007 ounces, 0.21 grams

SMC



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	SS52	SS53	SS54	SS55	SS56	SS58	SS510	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	20	30	40	50	60	80	100	V
Maximum RMS Voltage	VRMS	14	21	28	35	42	56	70	V
Maximum DC Blocking Voltage	VDC	20	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Lengths @TL=95 ℃	l(AV)	5.0							A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load(JEDEC Method)	IFSM	150							A
Maximum Forward Voltage at 5.0A DC	VF	0.45	0.55	0.6	0.7		0.85		V
Maximum DC Reverse Current @TJ=25℃ at Rated DC Bolcking Voltage @TJ=100℃	IR	1.0 50							mA
Typical Junction Capacitance (Note1)	CJ	500			350				pF
Typical Thermal Resistance (Note2)	RθJA	15			10				℃/W
Operating Temperature Range	TJ	-55 to +150							℃
Storage Temperature Range	TSTG	-55 to +150							℃

NOTES: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC

2. Thermal resistance junction to ambient,

FIG. 1 – FORWARD CURRENT DERATING CURVE

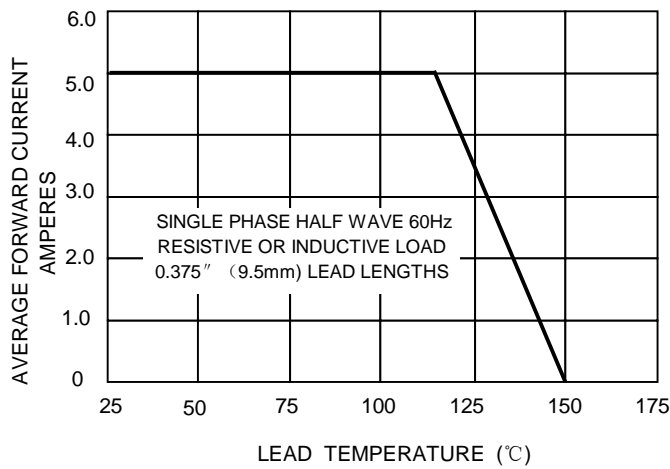


FIG. 2 – MAXIMUM NON-REPETITIVE SURGE CURRENT

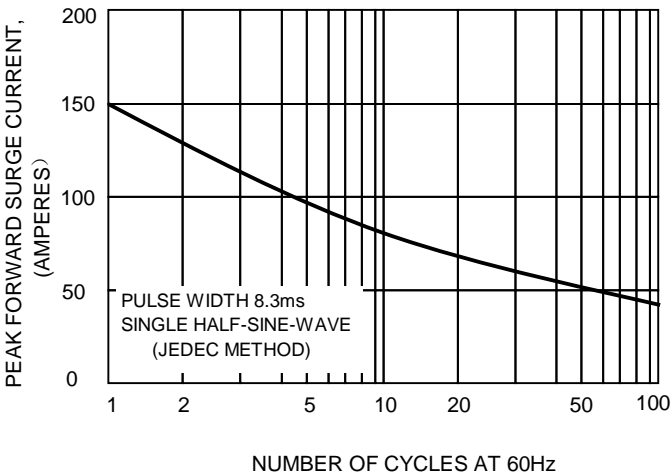


FIG.3 – TYPICAL JUNCTION CAPACITANCE

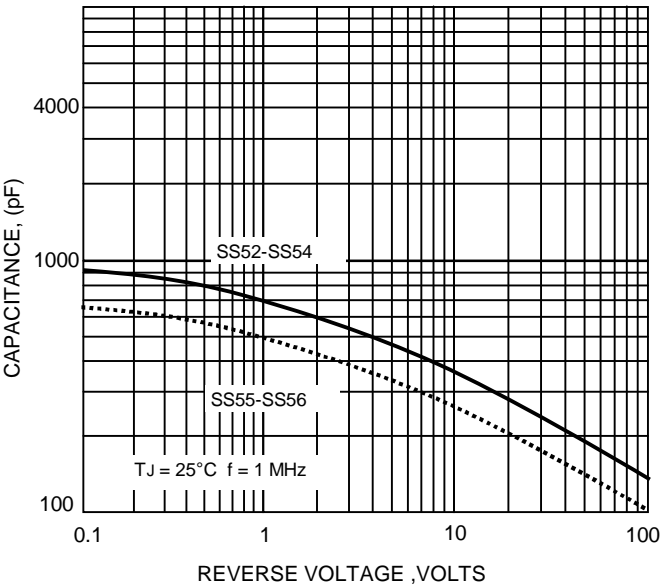


FIG.4-TYPICAL FORWARD CHARACTERISTICS

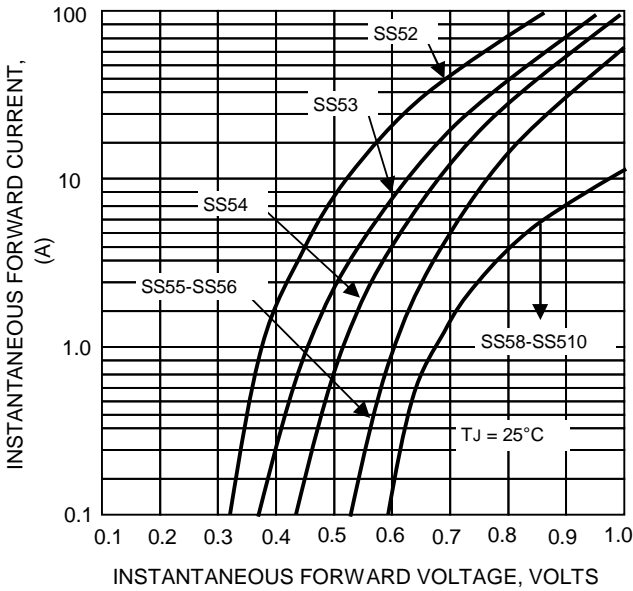


FIG.2-TYPICAL REVER CHARACTERISTICS

